

DOCKET NO.: 241014US2S DIV

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
KOICHI KOKUBUN : ATTN: APPLICATION DIVISION  
SERIAL NO: NEW APPLICATION :  
FILED: HEREWITH :  
FOR: SEMICONDUCTOR DEVICE :  
HAVING TRENCH CAPACITOR :  
FORMED IN SOI SUBSTRATE, :  
AND METHOD OF :  
MANUFACTURING THE SAME

PRELIMINARY AMENDMENT

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

Prior to an examination on the merits, please amend the above-identified patent application as follows:

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** are reflected in the listing of claims which begins on page 5 of this paper.

**Remarks** begin on page 9 of this paper.